

LM185-2.5/LM285-2.5/LM385-2.5 Micropower Voltage Reference Diode

General Description

The LM185-2.5/LM285-2.5/LM385-2.5 are micropower 2-terminal band-gap voltage regulator diodes. Operating over a 20 μ A to 20 mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM-185-2.5 band-gap reference uses only transistors and resistors, low noise and good long term stability result.

Careful design of the LM185-2.5 has made the device exceptionally tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185-2.5 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life. Further, the wide operating current allows it to replace older references with a tighter tolerance part. For applications requiring 1.2V see LM185-1.2.

The LM185-2.5 is rated for operation over a -55°C to 125°C temperature range while the LM285-2.5 is rated -40°C to 85°C and the LM385-2.5 0°C to 70°C. The LM185-2.5/LM285-2.5 are available in a hermetic TO-46 package and the LM285-2.5/LM385-2.5 are also available in a low-cost TO-92 molded package, as well as S.O. and SOT-23. The LM185-2.5 is also available in a hermetic leadless chip carrier package.

Features

- ±20 mV (±0.8%) max. initial tolerance (A grade)
- Operating current of 20 µA to 20 mA
- 0.6Ω dynamic impedance (A grade)
- Low temperature coefficient
- Low voltage reference—2.5V
- 1.2V device and adjustable device also available— LM185-1.2 series and LM185 series, respectively

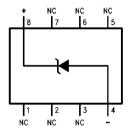
Connection Diagrams

TO-92 Plastic Package



Bottom View
Order Number LM285Z-2.5,
LM285BXZ-2.5, LM285BYZ-2.5
LM385Z-2.5, LM385AXZ-2.5
LM385AYZ-2.5, LM385BZ-2.5,
LM385BXZ-2.5 or LM385BYZ-2.5
See NS Package Number Z03A

SO Package



Order Number LM285M-2.5, LM285BXM-2.5, LM285BYM-2.5 LM385M-2.5, LM385BM-2.5 LM385BXM-2.5 or LM385BYM-2.5 See NS Package Number M08A



* Pin 3 is attached to the Die Attach Pad (DAP) and should be connected to Pin 2 or left floating.

Order Number LM385M3-2.5 See NS Package Number MA03B

Absolute Maximum Ratings (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Reverse Current 30 mA
Forward Current 10 mA
Operating Temperature
Range (Note 3)

 $\begin{array}{lll} \text{LM185-2.5} & -55^{\circ}\text{C to} + 125^{\circ}\text{C} \\ \text{LM285-2.5} & -40^{\circ}\text{C to} + 85^{\circ}\text{C} \\ \text{LM385-2.5} & 0^{\circ}\text{C to} \ 70^{\circ}\text{C} \\ \end{array}$

ESD Susceptibility (Note 9)	2kV
Storage Temperature	-55°C to + 150°C
Soldering Information	
TO-92 Package (10 sec.)	260°C
TO-46 Package (10 sec.)	300°C
SO and SOT Package	
Vapor Phase (60 sec.)	215°C
Infrared (15 sec.)	220°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

Electrical Characteristics

(Note 4)

Parameter	Conditions	Typ	LM389 LM385 LM385	Units	
	Conditions	Тур	Tested Limit (Note 5)	Design Limit (Note 6)	(Limits)
Reverse Breakdown Voltage	I _R = 100 μA	2.500	2.480 2.520	, ,	V(Min) V(Max)
		2.500		2.470 2.530	V(Min) V(Max)
Minimum Operating Current		12	18	20	μA (Max)
Reverse Breakdown Voltage Change with	$I_{MIN} \le I_{R} \le 1 \text{mA}$		1	1.5	mV (Max)
Current	1 mA ≤ I _R ≤ 20 mA		10	20	mV (Max)
Reverse Dynamic Impedance	I _R = 100 μA, f = 20 Hz	0.2		0.6 1.5	Ω
Wideband Noise (rms)	$I_{R} = 100 \mu\text{A}$ 10 Hz \le f \le 10 kHz	120			μV
Long Term Stability	$I_R = 100 \mu A,$ $T = 1000 Hr,$ $T_A = 25^{\circ}C \pm 0.1^{\circ}C$	20			ppm
Average Temperature Coefficient (Note 7)	$I_{MIN} \le I_{R} \le 20 \text{ mA}$ X Suffix Y Suffix		30 50		ppm/°C (Max)
	All Others			150	

Electrical Characteristics

Parameter	LM185-2.5 LM185BX-2.5 LM185BY-2.5 LM285-2.5 LM285-2.5 LM285BY-2.5 LM285BY-2.5		BX-2.5	2.5 LM385-2.5		Units (Limit)			
			Tested Limit	Design Limit	Tested Limit	Design Limit	Tested Limit	Design Limit	
			(Notes 5, 8)	(Note 6)	(Note 5)	(Note 6)	(Note 5)	(Note 6)	
Reverse Breakdown	T _A = 25°C,	2.5	2.462		2.462		2.425		V(Min)
Voltage	20 μA ≤ I _R ≤ 20 mA		2.538		2.538		2.575		V(Max)
Minimum Operating		13	20	30	20	30	20	30	μA
Current	LM385M3-2.5						15	20	(Max)
Reverse Breakdown Voltage	20 μA ≤ I _R ≤ 1 mA		1	1.5	2.0	2.5	2.0	2.5	mV (Max)
Change with Current	1 mA ≤ I _R ≤ 20 mA		10	20	20	25	20	25	mV (Max)
Reverse Dynamic Impedance	I _R = 100 μA, f = 20 Hz	1							Ω
Wideband Noise (rms)	I _R = 100 μA,	120							μV
	10 Hz ≤ f ≤ 10 kHz								
Long Term Stability	$I_R = 100 \mu A,$ $T = 1000 Hr,$ $T_A = 25^{\circ}C \pm 0.1^{\circ}C$	20							ppm
Average Temperature	I _R = 100 μA								
Coefficient (Note 7)	X Suffix Y Suffix		30 50	450	30 50	450		450	ppm/°C ppm/°C
	All Others			150		150		150	ppm/°C (Max)

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 2: Refer to RETS185H-2.5 for military specifications.

Note 3: For elevated temperature operation, $T_{J MAX}$ is:

LM185 150°C LM285 125°C LM385 100°C

Thermal Resistance	TO-92	TO-46	SO-8	SOT-23
θ _{ia} (Junction to Ambient)	180°C/W (0.4 Leads)	440°C/W	165°C/W	283°C/W
,	170°C/W (0.125 Leads)			
θ_{jc} (Junction to Case)	N/A	80°C/W	N/A	N/A

- Note 4: Parameters identified with boldface type apply at temperature extremes. All other numbers apply at T_A = T_J = 25°C.
- Note 5: Guaranteed and 100% production tested.
- Note 6: Guaranteed, but not 100% production tested. These limits are not used to calculate average outgoing quality levels.
- Note 7: The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures between the operating T_{MAX} and T_{MIN}, divided by T_{MAX}-T_{MIN}. The measured temperatures are -55°C, -40°C, 0°C, 25°C, 70°C, 85°C, 125°C.
- Note 8: A military RETS electrical specification available on request.
- Note 9: The human body model is a 100 pF capacitor discharged through a 1.5 $k\Omega$ resistor into each pin.

